

Description

The SSM3K333R uses advanced trench technology

to provide excellent R_{DS(ON)}, low gate charge and

operation with gate voltages as low as 4.5V. This

device is suitable for use as a

Battery protection or in other Switching application.



General Features

 $V_{DS} = 30V I_{D} = 5.8A$

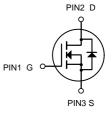
 $R_{DS(ON)}$ < 28m Ω @ V_{GS}=10V

Application

Battery protection

Load switch

Uninterruptible power supply



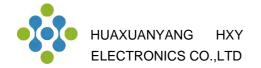
N-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
SSM3K333R	SOT-23-3L	HXY MOSFET	3000

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

symbol	parameter		unit
V _{DS}	Drain-source voltage		V
V _{GS}	Gate-source voltage		V
ID	Drain current-continuousª@Tj=125°C -pulse <i>d</i> ^b		А
IDM			А
ls	Drain-source Diode forward current		А
P _D	Maximum power dissipation	1.4	W
Tj	Operating junction Temperature range	-55—150	°C
Rth JA	Thermal Resistance junction-to ambient		°C/W



Electrical Characteristics (TA=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Drain-source breakdown voltage	BV _{DSS}	V _{GS} =0V, I _D =250μA	30	-	-	V
Zero gate voltage drain current	IDSS	V _{DS} =30V, V _{GS} =0V	-	-	1	μA
Gate-body leakage	IGSS	V _{DS} =0V, V _{GS} =±20V	-	-	±100	nA
Gate threshold voltage	VGS(th)	V _{DS} =V _{GS} , I _D =250μA	0.8	1.4	2.2	V
		V _{GS} =10V, I _D =5A	-	24	28	
Drain-source on-state resistance	RDS(ON)	V _{GS} =4.5V, I _D =4A		26	32	mΩ
Forward transconductance	gfs	V _{GS} =5V, I _D =5A	-	33	-	S
Input capacitance	Cıss	V _{DS} =15V ,V _{GS} =0V		255		pF
Output capacitance	coss	f=1.0MHz		45		
Reverse transfer capacitance	CRSS			35		
Turn-on delay time	tD(ON)		-	4.5	-	
Rise time	tr	V_{DS} =15V V_{GS} =10V RL=2.6 ohm R _{GEN} =3ohm	-	2.5	-	ns
Turn-off delay time	tD(OFF)		-	14.5	-	
Fall time	tf		-	3.5	-	
Total gate charge	Qg		-	5.2	-	
Gate-source charge	Qgs	V _{DS} =15V,I _D =5.8A	-	0.85	-	nC
Gate-drain charge	Qgd	V _{GS} =10V	-	1.3	-	
Diode forward voltage	V _{SD}	V _{GS} =0V,Is=1A	-	0.76	1.16	V

Notes:

- 1、surface mounted on FR4 board,t≤10sec
- 2、pulse test: pulse width≤300µs,duty≤2%
- $\ensuremath{\mathtt{3}}_{\times}$ guaranteed by design, not subject to production testing



Typical Performance Characteristics

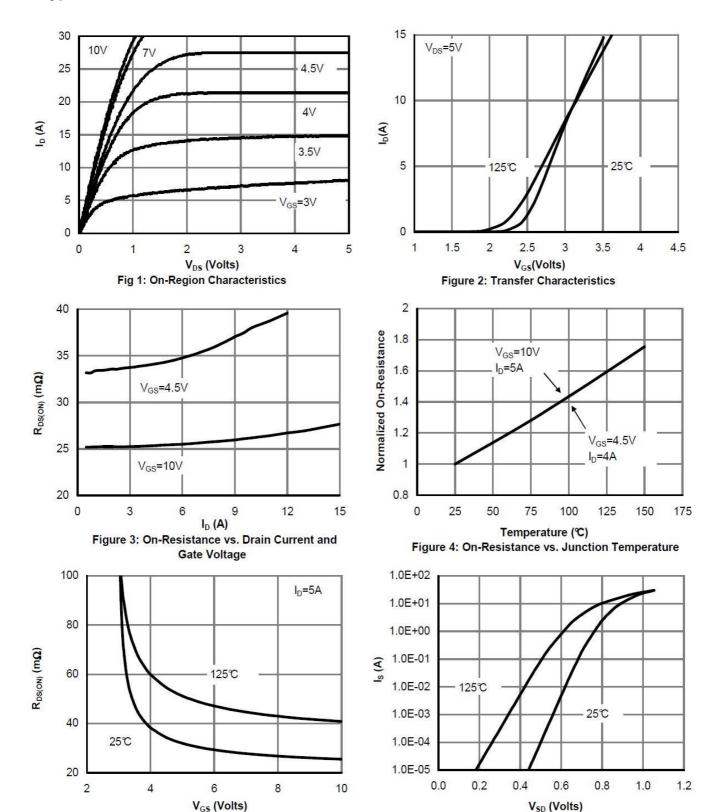
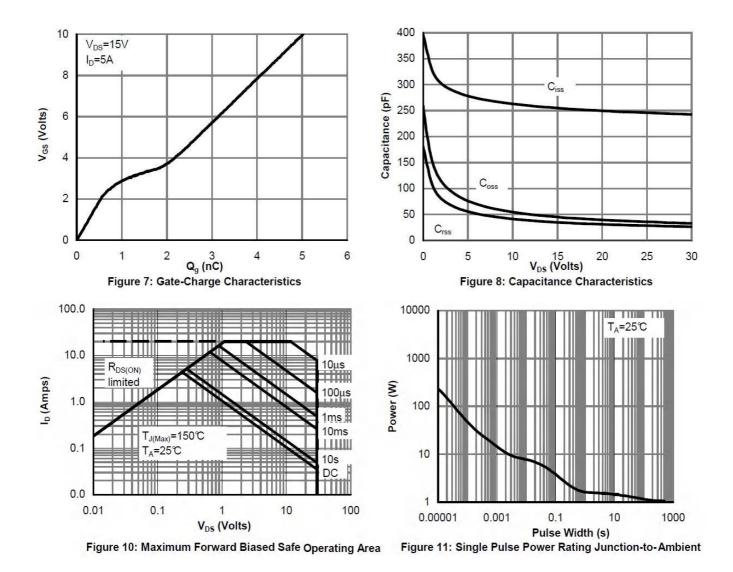
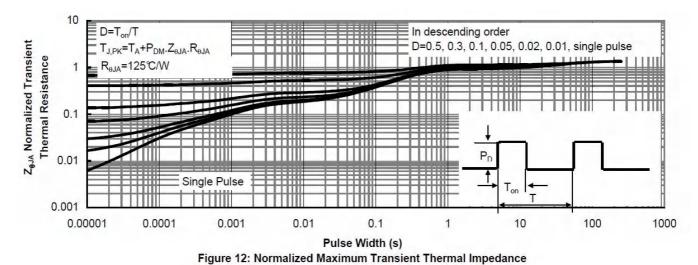


Figure 5: On-Resistance vs. Gate-Source Voltage

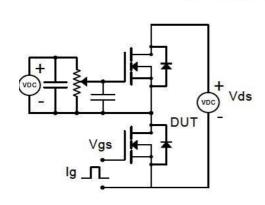
Figure 6: Body-Diode Characteristics

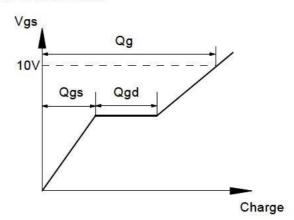






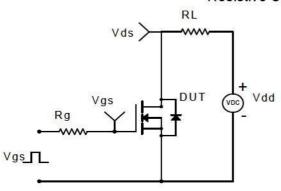
Gate Charge Test Circuit & Waveform

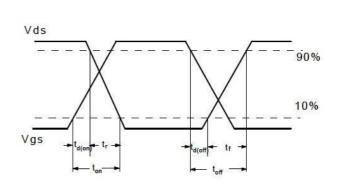




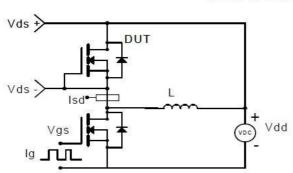
Resistive Switching Test Circuit & Waveforms

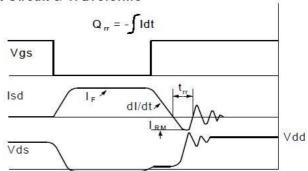
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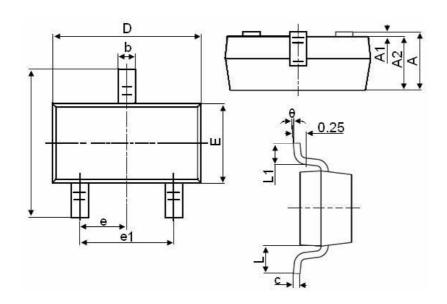


Diode Recovery Test Circuit & Waveforms





SOT-23-3LPackage Information



Symbol	Dimensions in Millimeters			
	MIN.	MAX.		
А	1.050	1.250		
A1	0.000	0.100		
A2	1.050	1.150		
b	0.300	0.500		
С	0.100	0.200		
D	2.800	3.000		
E	1.500	1.700		
E1	2.650	2.950		
е		0.950TYP		
e1	1.800	2.000		
L		0.550REF		
L1	0.300	0.600		
θ	0°	8°		



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